

CD4060B Types

CMOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

High-Voltage Types (20-Volt Rating)

■CD4060B consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-O's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of φ_{I} (and ϕ_0). All inputs and outputs are fully buffered. Schmitt trigger action on the line permits input-pulse input-pulse rise and fall times.

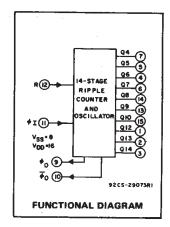
The CD4060B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- m 12 MHz clock rate at 15 V
- **■** Common reset
- Fully static operation
- Buffered inputs and outputs
- Schmitt trigger input-pulse line
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for description of "B" Series CMOS Devices"

Oscillator Features:

- All active components on chip
- RC or crystal oscillator configuration
- RC oscillator frequency of 690 kHz min. at 15 V



Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

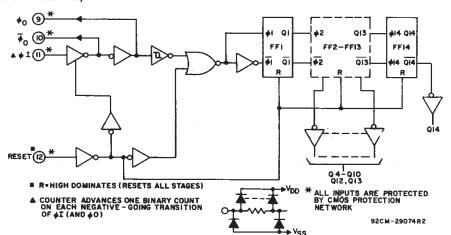


Fig.1 - Logic diagram.

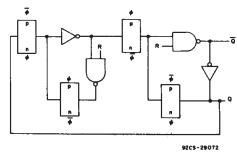
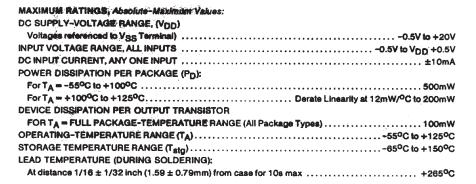


Fig. 2 — Detail of typical flip-flop stage.



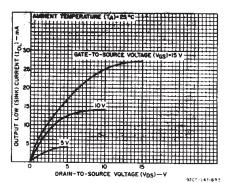


Fig. 3 — Typical n-channel output low (sink) current characteristics.

CD4060B Types

CHARAC- TERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
	vo	VIN	V _{DD}				1.77	+25			S
	(V)	(v)	(8)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent	_	0,5	5	5	-5	150	150		0.04	5	Г
Device		0,10	10	10	10	300	300		0.04	10	μı
Current,		0,15	15	20	20	600	600	1991 1	0.04	20	
IDD Max.	_	0,20	20	100	100	3000	3000	_	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1 .	-	Γ
(Sink)Ourrent*,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4.	3.4	6.8	_	
Output High (Source) Current*, IOH Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	m
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage:	. -	0,5	5		0	.05	-	0	0.05	Г	
Low-Level,	1 11.4	0,10	10		0	.05	_	0	0.05	1	
VOL Max.		0,15	15		0.	_	0	0.05	١,		
Output		0,5	5		4.	95	4.95	. 5	_	1	
Voltage:	-	0,10	10		9.	.95	9.95		_		
High-Level, VOH Min.	-	0,15	15		14.	.95	14.95	15	-		
Input Low	0.5,4.5	_	5	1.5						1.5	┢
Voltage	1,9	-	10			3	_	_	3	١	
VIL Max.	1.5,13.5	_	15			4	:	-		4	١,
Input High Voltage, V _{IH} Min.	0.5,4.5	_	5		:	3.5	_	-	1		
	1,9	_	10			7	_	-	1		
	1.5,13.5	ı	15			11 -		11	_	-	1
Input Current I _{IN} Max.	-	0,18	18	±0.1	±0.1	±1	.±1 . ,	_	±10-5	±0.1	μ

^{*}Data not applicable to terminal 9 or 10.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

CHARACTERISTIC	V _{DD}	LII	UNITS	
And the second second	100	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package Temperature Range)		3	18	٧
Input-Pulse Width, t _W (f = 100 kHz)	5 10 15	100 40 30	- - -	ns
Input-Pulse Rise Time and Fall Time, $t_{r\phi}$, $t_{f\phi}$	5 10 15	Unli	mited	-
Input-Pulse Frequency, f _φ T (External pulse source)	5 10 15	— — —	3.5 8 12	MHz
Reset Pulse Width, t _W	5 10 15	120 60 40	<u>-</u> -	ns

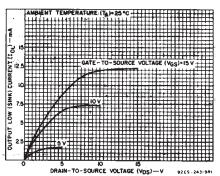


Fig. 4 — Minimum n-channel output low (sink) current characteristics.

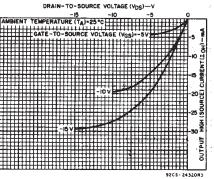


Fig. 5 — Typical p-channel output high (source) current characteristics.

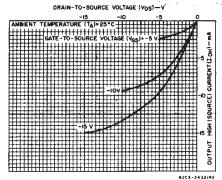


Fig. 6 - Minimum p-channel output high (source) current characteristics.

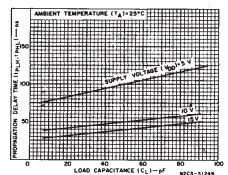


Fig. 7 — Typical propagation delay time $(Q_n \text{ to } Q_n+1)$ as a function of load capacitance.

CD4060B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T $_{A}$ = 25°C, Input t $_{r}$, t $_{f}$ = 20 ns, C $_{L}$ = 50 pF, R $_{L}$ = 200 k Ω

C[- 50 pr, n[- 200							
CHARACTERISTIC	TEST CONDITIONS	LIMITS				UNITS	
	CONDITIONS	V _{DD} (V)	MIN.	TYP.	MAX.	ONT	
Input-Pulse Operation						1.	
Propagation Delay		5	_	370	740		
Time, φ[to Q4 Out;		10	_	150	300		
tPHL, tPLH		15	_	100	200		
Propagation Delay		5	_	100	200		
Time, Q_n to Q_{n+1} ;		10		50	100		
tPHL, tPLH		15	-	40	80		
Transition Time,		5	-	100	200		
THL, TLH		10	. –	50	100	ns	
·		15		40	80		
Min. Input-Pulse	f = 100 kHz	5	_	50	100		
Width, tW		10		20	40		
		15		15	30		
Input-Pulse Rise & Fall		5					
Time, t _{rø} , t _{fø}	10] (Unlimited			
		15	. [.				
Max. Input-Pulse		5	3.5	7	-		
Frequency, for (External pulse)		10	8	16	_	MHz	
source)		15	12	24	_		
Input Capacitance, C ₁	Any Ing	out	_	5	7.5	pF	
Reset Operation							
Propagation Delay		5	1 -	180	360		
Time, tPHL		10	_	80	160		
		15		50	100	ns	
Minimum Reset		5	_	60	120		
Pulse Width, t _W		10		30	60		
		15	-	20	40		

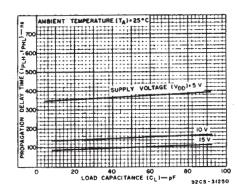


Fig. 8 — Typical propagation delay time ($\phi_{\rm j}$ to $\Omega_{\rm 4}$ Output) as a function of load capacitance.

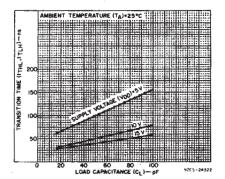


Fig. 9 — Typical transition time as a function of load capacitance.

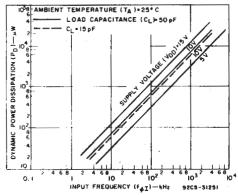


Fig. 10 — Typical dynamic power dissipation as a function of input frequency.

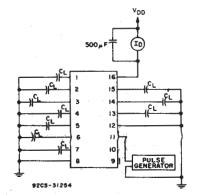


Fig. 11 - Dynamic power dissipation test circuit.

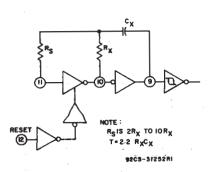


Fig. 12 - Typical RC circuit.

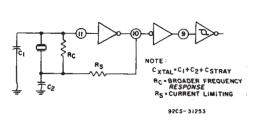


Fig. 13 - Typical crystal circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω [cont'd]

CHARACTERISTIC	CONDITIONS	V _{DD} (V)	Min.	Тур.	Max.	UNITS	
RC Operation	 						
Variation of Fre-	C _X = 200 pF,	5		23±10%	_		
quency (Unit-to-Unit)	$R_S = 560 \text{ k}\Omega$,	10	1	24±10%	_		
quency (Oint-to-Oint)	$R_X = 50 \text{ k}\Omega$	15	144	25±10%			
Variation of Fre-	C _X = 200 pF,	5V to 10 V		1.5		kHz	
quency with voltage	$R_S = 560 \text{ k}\Omega$,	10V to 15V		0.5	, —, , ,		
change (Same Unit)	$R_X = 50 \text{ k}\Omega$	100 10 150	- 0.5		_		
R _X max.	C _X = 10 μF	5	· -		20		
	= 50 μF	10	-	_	20	МΩ	
	= 10 μF	15		_	10		
C _X max.	R _X = 500 kΩ	5	_	_	1000		
	= 300 kΩ	10	_	<u> -</u>	50	μF	
	= 300 kΩ	15			50		
Maximum Oscillator	$R_X = 5 k\Omega$ $R_S = 30 k\Omega$	10	530	650	810	kHz	
Frequency*	C _X = 15 pF	15	690	800 940		7 Kmz	
Drive Current at							
Pin 9 (For Oscillator		i					
Design)	V _O = 0.4 V	5	0.16	0.35			
lor		10	0.42	0.8	_		
	= 1.5 V	15	1	2	-	mA	
	V _O = 4.6 V	5	-0.16	-0.35	_		
[‡] ОН	= 9.5 V	10	-0.42	0.8	-		
	= 13.5 V	15	-1	-2	_		

^{*}RC oscillator applications are not recommended at supply voltages below 7 V for $R_{\mbox{\scriptsize X}} < 50 \ k\Omega_{\star}$

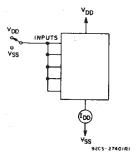


Fig. 14 - Quiescent device current.

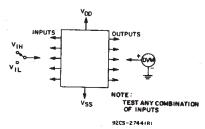


Fig. 15 — Input voltage.

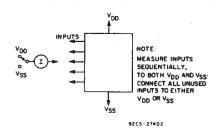
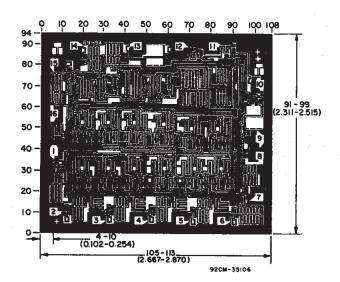
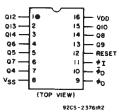


Fig. 16 - Input current.







Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

Chip dimensions and pad layout for CD4060B

PACKAGE OPTION ADDENDUM



26-Sep-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
CD4060BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4060BF	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4060BF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4060BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

26-Sep-2005

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14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

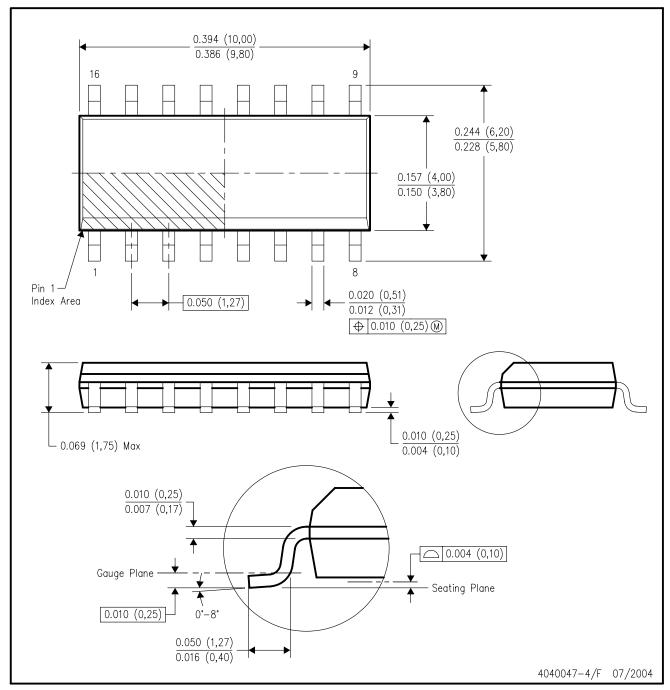


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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